

# APPLICATION DATA SHEET

Electronic Version 0.0.11

Stylesheet Version: 1.0

Attorney Docket Number: EMEP0021USA

Publication Filing Type: new-utility

Application Type: utility

Title of Invention: STRUCTURE OF AN EMBEDDED CHANNEL WRITE/ERASE FLASH  
MEMORY CELL AND FABRICATING METHOD THEREOF

Customer Number Attorney: 027765



Customer Number Correspondence Address: 027765



## Continuity Data:

This application is a division of 09/865,432 2001-05-29 pending

## Foreign Priority:

09/865,432                      US      2001-05-29                      Priority Claimed

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